Metal silylene complexes have been proposed as intermediates in numerous catalytic reactions. While several routes to M=Si complexes have been established, the direct generation of silylenes from silanes (by oxidative addition of Si–H, followed by 1,2-hydrogen migration to the metal) appears to be crucial to their involvement in catalytic reactions. We recently reported evidence for a new hydrosilation mechanism catalyzed by the cationic ruthenium silylene complex [ Cp*(Pr,P)(H)Ru=SiHPh-CH=O][B(C6F5)4]. The proposed pathway involves activation of two Si–H bonds to form a hydrogen-substituted silylene complex, followed by direct addition of an sp3 Si–H bond to the alkene, H-migration from the metal center, and finally, reductive elimination of the hydrosilation product. To further our mechanistic understanding of this catalysis, we explored the influence of electronic charge on reactivity of the Si–H group, neutral osmium silylene complexes were targeted.

The pathway to neutral osmium silylene complexes is outlined in Scheme 1. The 16-electron complex Cp*(Pr,P)OsBr (1) reacted with 0.5 equiv of Mg(CH2Ph)2(THF)2 to cleanly generate the corresponding benzyl species Cp*(Pr,P)OsCH2Ph (2). Complex 2 is thermally unstable, and definitive NMR assignments could not be obtained due to fluxional behavior in solution. Thus, additional evidence for the identity of 2 was obtained by its conversion to the 18-electron CO adduct 3 (v(CO) = 1883 cm−1) in 42% yield. The 1H NMR spectrum of 3 is consistent with the presence of an η6-benzyl group.

Compound 2 readily activates the Si–H bonds of silanes. Treatment of a toluene solution of 2 with sterically encumbered MesSiH (Mes = mesityl) afforded 1 equiv of toluene and the ortho-methyl-activated silyl complex Cp*(Pr,P)(H)OsMesSiH2Mes (5% yield as identified by 1H, 13C, 29Si, and 31P NMR and IR spectroscopy). More sterically demanding primary silanes were used to bias the formation of silylene complexes over C–H activation. Reaction of 2 with tripSiH3 (tripl = 2,4,6-Pr3C6H2) led to exclusive formation of the desired primary silylene complex Cp*(Pr,P)(H)Os=SiH(tripl) (4), which was isolated as analytically pure orange crystals in 69% yield. Similarly, reaction of 2 with dmpSiH3 (dmp = 2,6-Mes2C6H2) provided Cp*(Pr,P)(H)Os=SiH(dmp) (5) as a crystalline orange solid. Complexes 4 and 5 were also prepared by the two-step reaction sequence involving oxidative addition of the silane to 1, followed by addition of Mg(CH2Ph)2(THF)2 (Scheme 1).

Complex 4 exhibits characteristic 1H NMR shifts at 12.1 ppm (SiH) and −16.0 (OsH), and a downfield 29Si NMR shift of 229 ppm. A very low 2JSiH value of 7.7 Hz suggests that any interaction between the silicon and the metal hydride is minimal. Analogous spectroscopic features were observed for 5. The molecular structure of 4 (Figure 1) features a unusually short Os–Si separation of 2.219(2) Å. Planarity at silicon is indicated by the summation of angles about this atom (359.8°). The osmium- and silicon-bound hydrogen atoms, which were located in the Fourier difference map, adopt an approximately cis geometry with a H(1)–Os–Si–H(2) dihedral angle of 53.2(4)°.

As reported previously, the cationic analogue of 4, [Cp*(Pr,P)(H)2Os=SiH(trip)][B(C6F5)4] (8), rapidly reacts with alkenes at −78 °C via insertion into the Si–H bond. This reaction appears to model a key step in the catalytic hydrosilation of alkenes by [Cp*(Pr,P)(H)2Ru=SiHPh]+. To probe the mechanism of this transformation, the kinetic isotope effect (KIE) was determined by a competition experiment involving reaction of 8 and [Cp*(Pr,P)(D)2Os=SiH(trip)][B(C6F5)4] (8-d) with 0.5 equiv of 1-hexene. This experiment established an inverse KIE of kH/kD = 0.8(1), which indicates significant sp2 → sp3 hybridization at silicon during approach to the transition state for insertion into the Si–H bond.

Interestingly, the neutral silylene complex 4 is much less reactive than 8 toward olefins. Thus, no reactions were observed between 4 and ethylene, 1-hexene, cyclohexene, and 2-butene over the course of 120 h at room temperature in benzene-d8. Upon heating a toluene-d8 solution of 4 and 1-hexene to 80 °C, 4 was observed to decompose after 72 h, with no consumption of the alkene. This dramatic difference in reactivity between 4 and its protonated analogue 8 prompted an investigation of these Si–H bond additions using computational methods.

Calculations5 utilized the DFT B3LYP approach and targeted the model Os complexes Cp(H,P)(H)Os=SiH2 (A) and [Cp(H,P)(H)2-
Os=SiH₂⁺ (D). Analysis of the coordination and insertion pathways revealed exergonic processes similar to those found for [Cp(H₃P)(H)₂Ru=SiH₂]⁺. However, coordination of ethylene to A is ca. 8 kcal mol⁻¹ higher in energy than the coordination of ethylene to D. Additionally, the transition state for insertion into the Si–H bond is 18 kcal mol⁻¹ higher in energy for A vs D (Scheme 2). These values suggest that there is a significant kinetic barrier to both olefin coordination and insertion for the neutral silylene species.

 Orbital analyses of A and D demonstrated that the LUMOs for both species are primarily silicon p-orbitals, and the LUMO of D (–0.051 eV) is much closer in energy than the LUMO of A (–0.051 eV) to the HOMO of ethylene (–0.267 eV). This small HOMO–LUMO gap allows for enhanced binding of ethylene to the cationic species D (Table 1). The large reorganization energy associated with insertion of ethylene into the Si–H bond of A arises in part from the substantial electronic and structural changes required for the transformation of B to TS₁ (Table 1). In particular, the difference between the Si–C bond lengths in B and TS₁ was determined to be 1.33 Å, whereas there was only a change of 0.39 Å between E and TS₂. In the case of D, these smaller geometric and electronic changes give rise to a lower transition-state energy (TS₂ = 6.3 kcal mol⁻¹).²

 Increased positive charge on the Si(H₃P)(H)₂Os fragment is generated by shifting electron density to Cp(H₃P)(H) in reducing the Os–Si bond length. It should be noted that the increase in positive charge on the silicon fragment corresponds to an increase in Os⁺² character for the neutral complexes and Os⁺⁺ character for the cationic complexes. Thus, it is hypothesized that the difference in reactivity stems from the importance of the resonance contributor that establishes a positive charge at silicon (Scheme 3), rendering the silyl fragment iso-electronic with a boryl group. It is well established that boryl functionalities readily hydroborate unsaturated molecules by direct addition of a B–H bond.³

The reported results above concern an interesting type of transformation, in which a transition metal center activates one substrate toward direct reaction with another, without prior coordination of the second substrate to the metal center.⁴ In particular, a dramatic example of the influence of charge distribution on the reactivity of a metal silylene complex has been observed. This information should be of use in the design of additional catalytic reactions that may occur via direct addition of a metal-activated element—hydrogen bond to an unsaturated substrate.

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Supporting Information Available: Crystallographic data (tables and CIF) for 4; experimental and computational details, calculated structures for ethylene coordination to osmium, JIMP representations of the calculated structures, figures depicting all resonance structures from Scheme 3, and GaussView illustrations of the LUMO of A and D. This material is available free of charge via the Internet at http://pubs.acs.org.

References


(4) All calculations were conducted using the Gaussian 03 suite of programs: Frisch, M. J.; et al. Gaussian 03, Revision B.04; Gaussian, Inc.: Wallingford CT, 2004.